



Plasma II

L13: Plasma diagnostics 2

H. Reimerdes

- Introduction
- Passive measurements
 - EM emission
 - Bremsstrahlung
 - Line emission
 - Synchrotron radiation
 - Cyclotron emission
 - Magnetic fields
- **Active measurements**
 - Langmuir probes
 - Interferometry
 - Thomson scattering
- **Appendix**



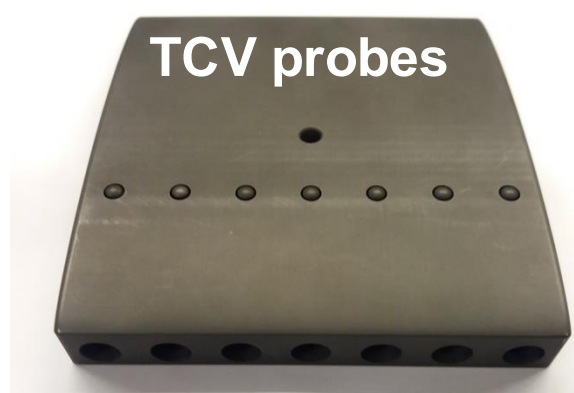
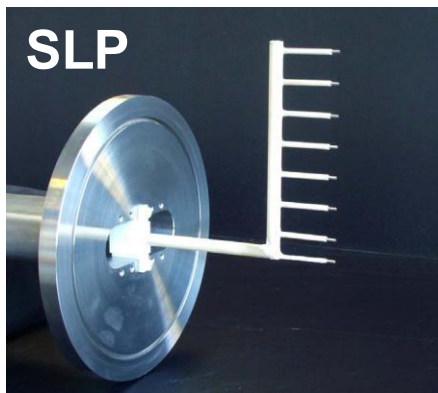
Plasma diagnostics 1



Plasma diagnostics 2

- I.H. Hutchinson, “*Principles of plasma diagnostics*”, Second edition, Cambridge University Press

- One of the simplest and certainly one of the most widely used plasma diagnostics
 - Not necessarily easy to interpret



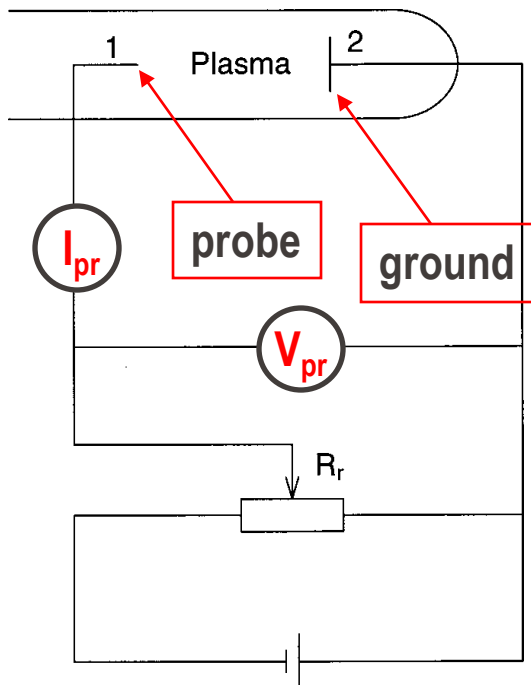
- Associated with Irving Langmuir who was one of the first to use electric probes to sense plasma fluxes

Irving Langmuir (1881-1957),
American chemist, Physicist and
engineer.

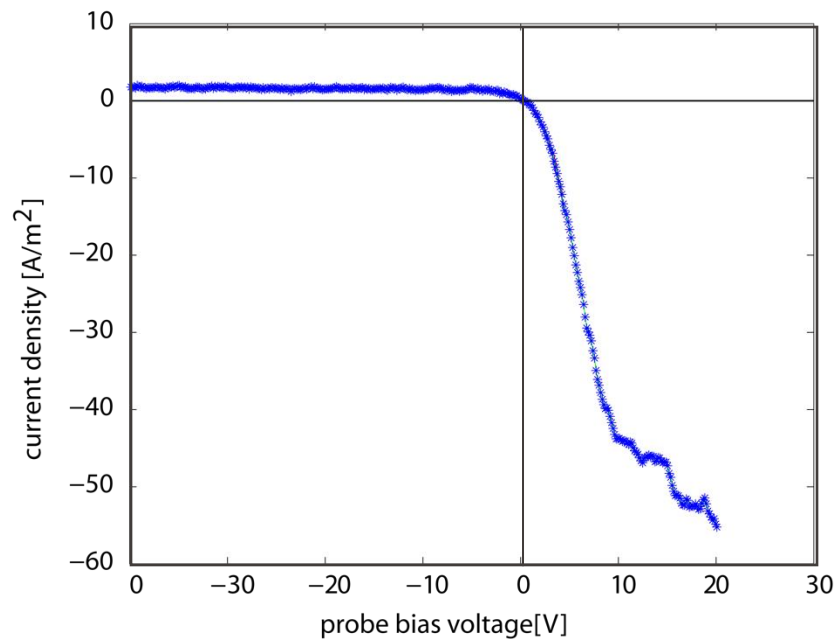
- Originator of the term 'plasma'
- Nobel prize in chemistry 1932

Langmuir probes measure a current as a function of an applied potential

- Circuit diagram

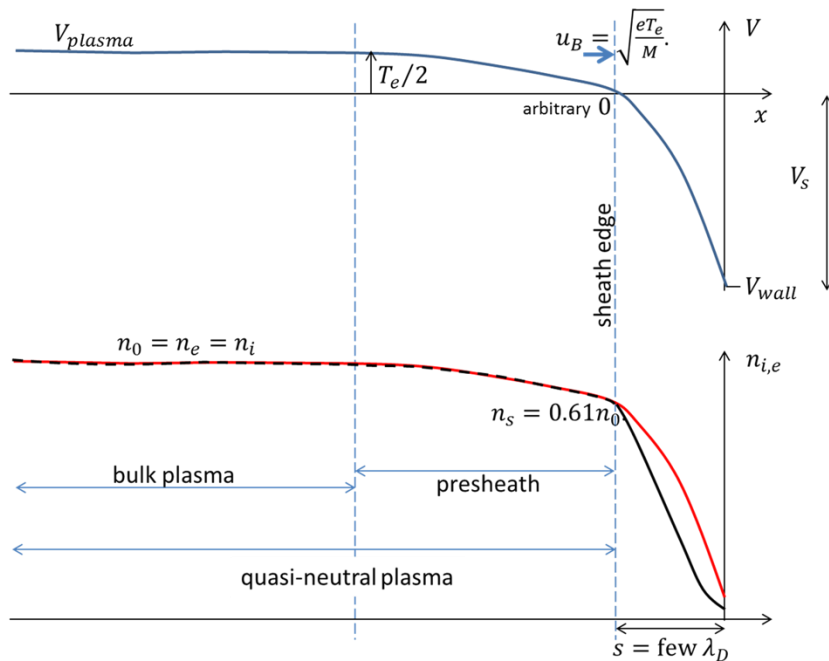


- Typical I-V curve



- Floating wall

$$V_{\text{plasma}} = +k_B T_e / 2e$$



$$V_{\text{sheath-entrance}} = 0$$

$$V_{\text{wall}} = -\frac{k_B T_e}{2e} \ln\left(\frac{M}{2\pi m_e}\right)$$

$= V_{\text{float}}$

Langmuir probes

Theory

■ Plasma sheath (L8)

- Ion flux to the wall:
- Electron flux to the wall:

$$\Gamma_i = n_s u_B = n_s \sqrt{\frac{k_B T_e}{M}} = n_s \frac{\bar{v}_e}{4} \exp\left(\frac{eV_{\text{float}}}{k_B T_e}\right)$$

$$\Gamma_e = n_{e,\text{wall}} \frac{\bar{v}_e}{4} = n_s \frac{\bar{v}_e}{4} \exp\left(\frac{eV_{\text{wall}}}{k_B T_e}\right)$$

Eq. that we used to determine V_{float} (potential of a floating wall)

General case:
Allow V_{wall} to deviate from V_{float}

■ Current density

$$j = e(\Gamma_i - \Gamma_e) = en_s \frac{\bar{v}_e}{4} \left[\exp\left(\frac{eV_{\text{float}}}{k_B T_e}\right) - \exp\left(\frac{eV_{\text{wall}}}{k_B T_e}\right) \right]$$

$$= en_s \frac{\bar{v}_e}{4} \exp\left(\frac{eV_{\text{float}}}{k_B T_e}\right) \left[1 - \exp\left(\frac{e(V_{\text{wall}} - V_{\text{float}})}{k_B T_e}\right) \right]$$

$$n_s u_B$$

No current when
 $V_{\text{wall}} = V_{\text{float}}$
(as expected)

Langmuir probes

Interpretation of I-V curve

- Current density

$$I_{\text{pr}} = A_{\text{pr}} j = \underbrace{A_{\text{pr}} e n_s u_B}_{I_{\text{sat}}} \left[1 - \exp \left(- \frac{e(V_{\text{wall}} - V_{\text{float}})}{k_B T_e} \right) \right]$$

Potential of surrounding wall – usually used as ground for the probe

Probe bias : negative bias only suppresses electron current, but cannot draw more ion current

Langmuir probes

Interpretation of I-V curve

- Current density

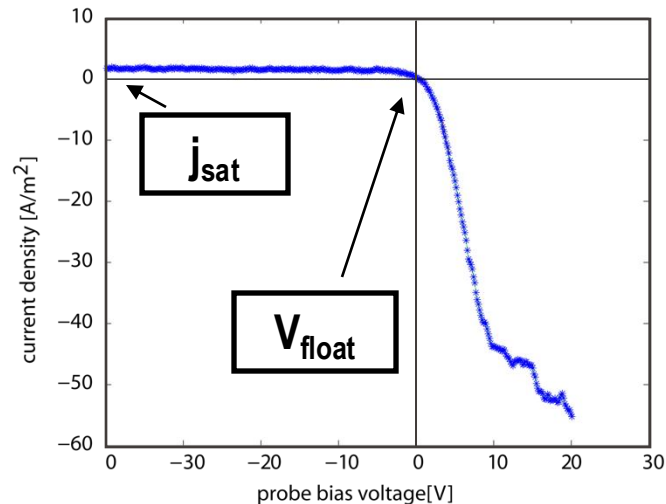
$$j_{pr} = j_{sat} \left[1 - \exp \left(\frac{e(V_{bias} - V_{float})}{k_B T_e} \right) \right]$$

- With ion saturation current

$$j_{sat} = en_s u_B$$

- Particle flux to the wall

$$\Gamma_{wall} = n_s u_B = j_{sat}/e$$



Langmuir probes

Interpretation of I-V curve

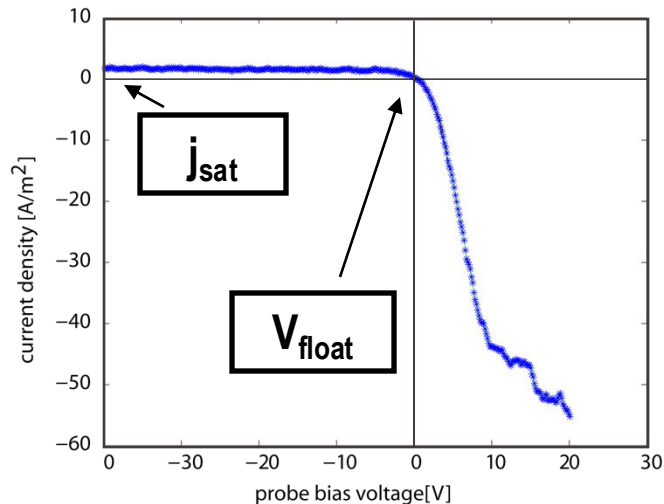
- Current density

$$j_{\text{pr}} = j_{\text{sat}} \left[1 - \exp \left(\frac{e(V_{\text{bias}} - V_{\text{float}})}{k_B T_e} \right) \right]$$

- With ion saturation current

$$j_{\text{sat}} = en_s u_B$$

- Electron temperature T_e determined from logarithmic slope of $j_{\text{pr}} = f(V_{\text{bias}})$



Langmuir probes

Interpretation of I-V curve

- Current density

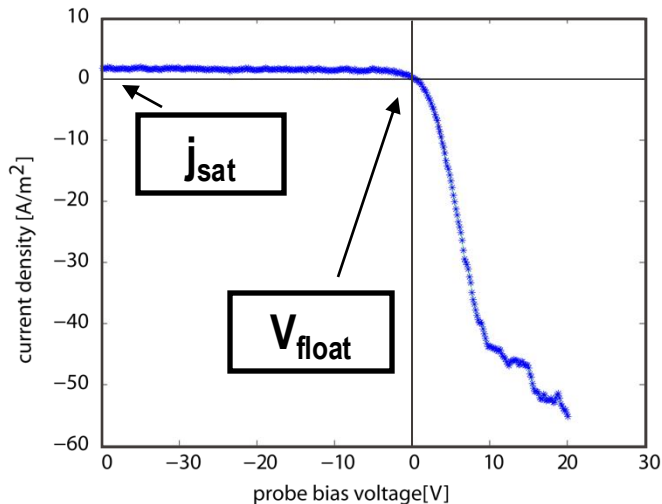
$$j_{pr} = j_{sat} \left[1 - \exp \left(\frac{e(V_{bias} - V_{float})}{k_B T_e} \right) \right]$$

- With ion saturation current

$$j_{sat} = en_s u_B$$

3. Plasma density

$$\begin{aligned} n_0 &= \frac{n_s}{0.61} = \frac{j_{sat}}{0.61 e} \sqrt{\frac{M}{k_B T_e}} \\ &= \frac{j_{sat}}{0.61 e} \sqrt{\frac{M}{k_B T_e (1 + T_i/T_e)}} \end{aligned}$$



if $T_i > 0$

Langmuir probes

Interpretation of I-V curve

- Current density

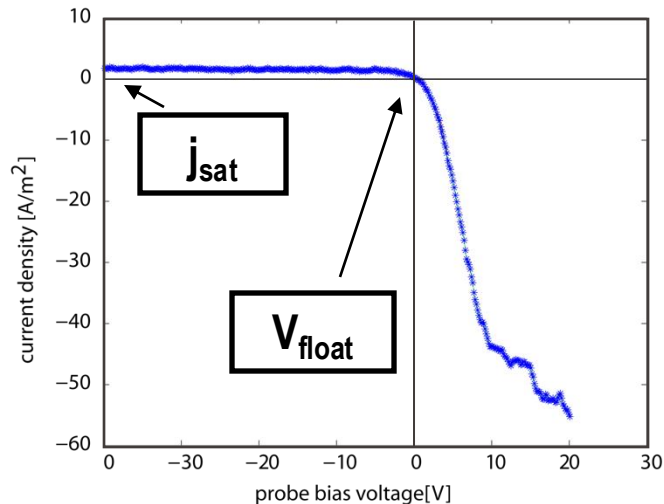
$$j_{pr} = j_{sat} \left[1 - \exp \left(\frac{e(V_{bias} - V_{float})}{k_B T_e} \right) \right]$$

- With ion saturation current

$$j_{sat} = en_s u_B$$

4. Plasma energy loss (evaluated at sheath entrance)

$$q_{se} = \left[\frac{5}{2} k_B T_i + \frac{1}{2} M u_B^2 \right] \frac{j_{sat}}{e} + [2k_B T_e + e(|V_{sheath}|)] \frac{j_{sat}}{e} + E_{pot} \frac{j_{sat}}{e}$$



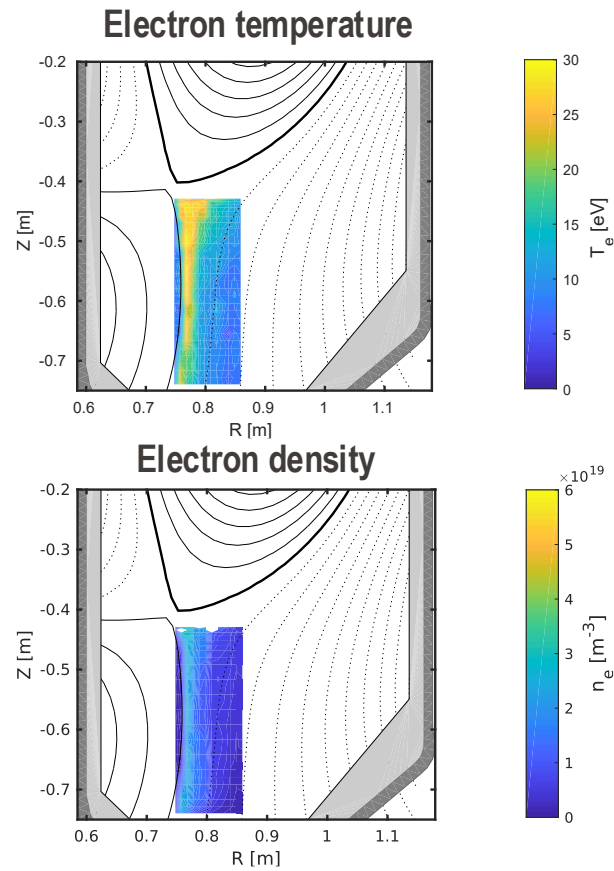
Langmuir probes

Examples

- Wall mounted
- Movable probes
 - Ex. TCV's reciprocating divertor probe arrays (RDPA)



[Courtesy of H. De Oliveira]



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Plasma diagnostics 1



Plasma diagnostics 2

Interferometry theory

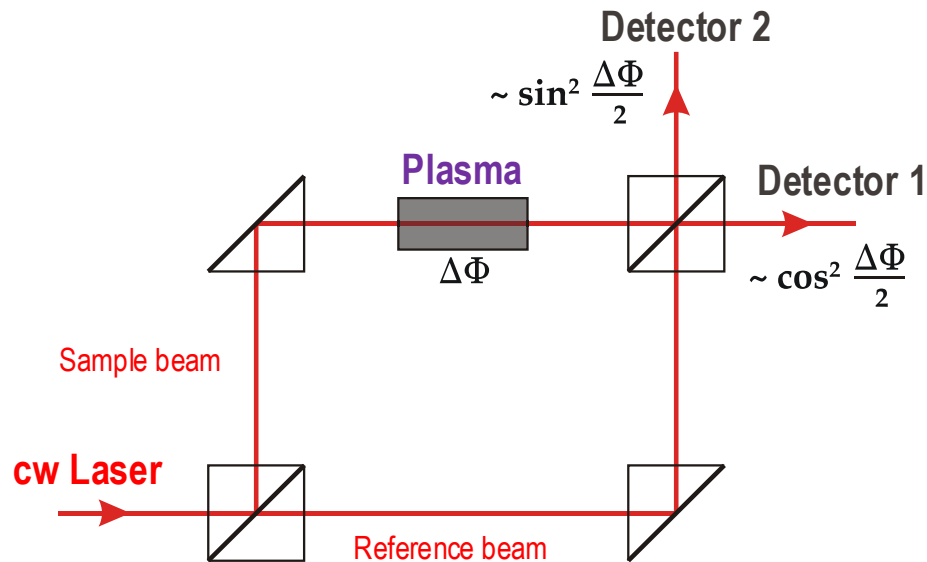
- Use propagation of light through a plasma to infer its density

- Refractive index $N = \sqrt{1 - \frac{\omega_{p,e}^2}{\omega^2}}$ with electron plasma frequency $\omega_{p,e} = \sqrt{\frac{n_e e^2}{\epsilon_0 m_e}}$

- Measure phase shift $\Delta\phi$ with a **Mach-Zehnder interferometer**

- Split coherent light into sample and reference beams

- Without phase shift beams interfere constructively at detector 1 and destructively at detector 2
- Absolute phase shift known up to $\pi \rightarrow$ Need to keep track of multiples of $\pi \rightarrow$ count fringes
- Ambiguity of phase change direction, when $\Delta\phi = 0, \pi, 2\pi, \dots$



Source: Ansgar Hellwig,

<https://commons.wikimedia.org/w/index.php?curid=348005>

- Measure phase shift $\Delta\phi$ with a ***Mach-Zehnder interferometer***
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- **Faraday rotation:** Right and left circularly polarised light travelling parallel to a magnetic field in a plasma have different refractive indices

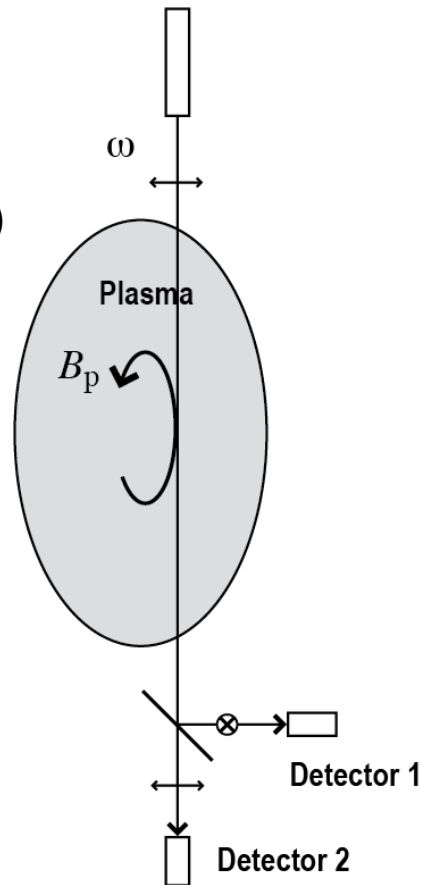
$$n_{L,R} = \sqrt{1 - \frac{\omega_{p,e}^2}{\omega^2 \pm \omega \Omega_e}} \quad \text{with} \quad \Omega_e = \frac{eB}{m_e} \quad \text{and} \quad \omega_{p,e} = \sqrt{\frac{n_e e^2}{m_e \epsilon_0}}$$

The **polarisation angle** θ of linearly polarized light **rotates**. The rotation angle is proportional to

$$\Delta\theta_F \propto \lambda^2 \int n_e \mathbf{B} \cdot d\mathbf{l}$$

- Faraday rotation in typical fusion plasmas is small $\Delta\theta_F \ll \pi \rightarrow$ requires sensitive detection technique

- In typical fusion plasmas Faraday rotation is measured using light in the far-infrared ($100 - 400\mu m$)
- Simple polarimeter scheme:
 - Linearly polarized light is passed through a plasma
 - Faraday rotation changes the polarisation angle
 - A polarisation sensitive beam splitter separates orthogonal components
 - Ratio of amplitudes at detector 1 and 2 yields the Faraday rotation
- Various other detection techniques have been developed



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Plasma diagnostics 2

Thomson scattering theory

- Use scattering of laser light propagating through a plasma to infer electron temperature
- Scattering of light on free charges in the classical limit ($h\nu \ll mc^2$) is referred to as **Thomson scattering**
 - Charges (primarily electrons) accelerating in the time-varying electric field of an incoming e-m wave emit e-m radiation (scattered light)
 - Cross section for scattering on free-electron $\sigma_{\text{TS}} = \frac{8}{3}\pi r_c^2$ with $r_c = \frac{e^2}{4\pi\epsilon_0 m_e c^2}$ being the classical electron radius is small (**see L9**)
 - Only a small fraction ($\sim 10^{-11}$) of the laser light is scattered

Thomson scattering theory

- Equation of motion for an electron

$$m_e \frac{d\vec{v}}{dt} = -e\vec{E}_i$$

- Emits an e-m wave

$$\vec{E}_s = -\frac{e}{4\pi\epsilon_0} \left[\frac{1}{c^2 R} \hat{s} \times \left(\hat{s} \times \frac{d\vec{v}}{dt} \right) \right] = \frac{e}{4\pi\epsilon_0 m_e c^2 R} [\hat{s} \times (\hat{s} \times \vec{E}_i)] = \frac{r_c}{R} [\hat{s} \times (\hat{s} \times \vec{E}_i)]$$

- Emitted power depends on scattering direction

$$\frac{dP}{d\Omega_s} = R^2 c \epsilon_0 |\vec{E}_s|^2 = r_c^2 c \epsilon_0 \sin^2 \phi |\vec{E}_i|^2$$

- Polarise incident laser light perpendicular to observation direction

Thomson scattering spectrum

- Spectrum for a Maxwellian electron velocity distribution

$$\frac{d^2 P}{d\omega d\Omega_s} = r_c^2 n_e P_i L \sin^2 \phi S(\bar{k}, \omega)$$

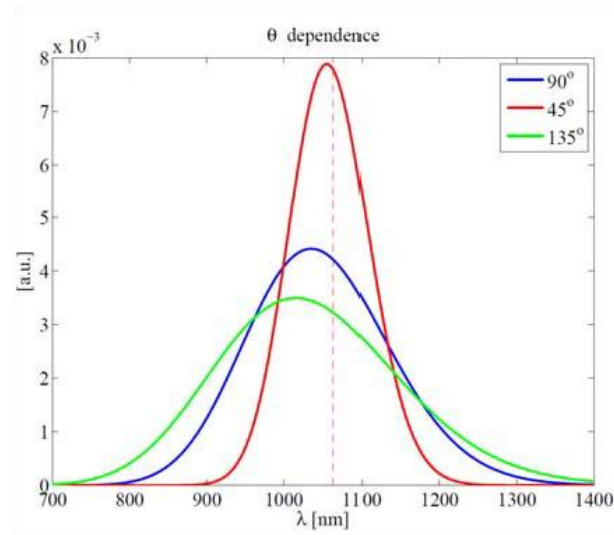
- With spectral form factor S

- Thermal motion of electrons broaden spectrum of scattered light

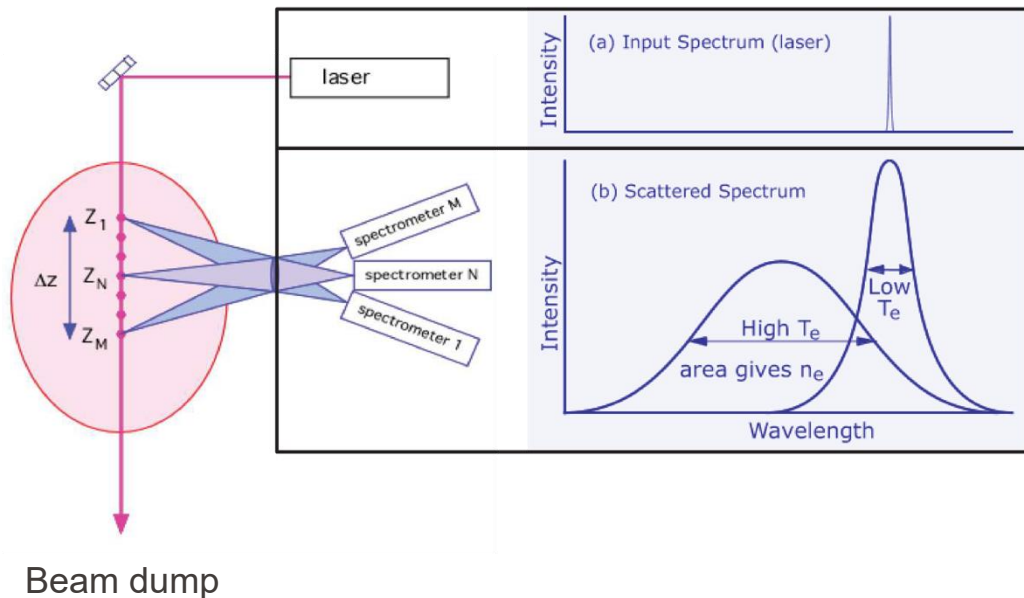
- Spectrum yields electron temperature

$$\Delta\lambda_{\text{FWHM}} = 4\varepsilon\lambda_0 \sin\frac{\theta}{2} \sqrt{\frac{2k_B T_e \ln 2}{m_e c^2}}$$

- Depends on observation angle θ



Thomson scattering setup



- Broadening yields electron temperature
- Intensity yields electron density

$$n_e \propto \int P(\bar{k}, \omega) d\omega$$

- Low scattering cross section requires high power laser → pulsed operation
- TS diagnostic practically non-perturbative!

- Errors

■ **Systematic errors**

- Consistent and reproducible (e.g. calibration error)
- Cannot be revealed through repeated measurements
- Compare different measurements (technique or instrument) of same parameter
- Estimate from knowledge of technique

■ **Statistical errors**

- Random (e.g. fluctuations in electronics)
- Can be revealed by repeated measurements

■ **Human errors**

- Random (e.g. noting the wrong number)
- Care and self-correction

Accuracy vs. Precision

- Accuracy – deviation from reality
- Determined by all errors
- Precision – reproducibility
- Determined by statistical errors

- Set of N repeated measurements of same parameter – *sample*

- Mean value of sample

$$\mu_N = \frac{1}{N} \sum_{i=1}^N x_i$$

- Standard deviation of sample

$$\sigma_N = \left[\frac{1}{(N-1)} \sum_{i=1}^N (x_i - \mu_N)^2 \right]^{1/2}$$

- Increasing the sample size will lead to constant values μ_N and σ_N – characteristic of the random distribution of the parameters

- μ : Associated with ‘real’ value of parameter
- σ : Statistical uncertainty of each measurement x_i

[I.H. Hutchinson, “Principles of plasma diagnostics”, Appendix 2]

Reduce uncertainty of estimate

- If σ is the standard deviation of measurements x_i , μ_N becomes a random variable described by a Gaussian probability distribution with a standard deviation $\sigma/\sqrt{N}$
- Standard deviation (uncertainty!) of sample mean decreases with **number of measurements** in each set -> **standard error**

$$s_N = \frac{\sigma_N}{\sqrt{N}} = \left[\frac{1}{N(N-1)} \sum_{i=1}^N (x_i - \mu_N)^2 \right]^{1/2}$$

- Increase accuracy with more measurement until systematic error dominates – further increase only increases precision, but not accuracy

[I.H. Hutchinson, “Principles of plasma diagnostics”, Appendix 2]

Textbooks

- J. Wesson, “Tokamaks”, Third edition, Oxford Science Publications – Chapter 10 ← *Good overview*
- I.H. Hutchinson, “Principles of plasma diagnostics”, Second edition, Cambridge University Press ← *Very detailed description based on first principles, goes well beyond course content*